











#### SN54LVC573A, SN74LVC573A

SCAS300S - JANUARY 1993-REVISED MAY 2014

## SNx4LVC573A Octal Transparent D-Type Latches With 3-State Outputs

#### **Features**

- Operate From 1.65 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max t<sub>pd</sub> of 6.9 ns at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce)  $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)  $> 2 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Support Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V<sub>CC</sub>)
- Ioff Supports Live Insertion, Partial Power Down Mode, and Back Drive Protection
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

## **Applications**

- Servers
- PC, Notebook
- Network Switch
- Health & Fitness/Wearables
- Telecom Infrastructure
- Electronic Point of Sales

## 3 Description

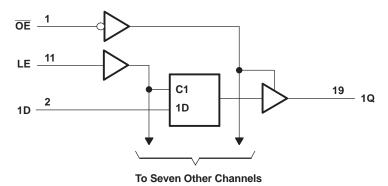
The SN54LVC573A octal transparent D-type latch is designed for 2.7-V to 3.6-V V<sub>CC</sub> operation, and the SN74LVC573A octal transparent D-type latch is designed for 1.65-V to 3.6-V V<sub>CC</sub> operation. These devices feature 3-state outputs designed specifically for driving highly capacitive or relatively lowimpedance loads. They are particularly suitable for implementing buffer registers, input/output (I/O) ports, bidirectional bus drivers, and working registers.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	PDIP (20)	25.40 x 6.35 mm
	VQGN (20)	4.50 x 3.50 mm
SN74LVC573A	SOIC (20)	12.80 x 7.50 mm
	SSOP (20)	7.20 x 5.30 mm
	TVSOP (20)	5.00 x 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

## Simplified Schematic



Pin numbers shown are for the DB, DGV, DW, FK, J, N, NS, PW, RGY, and W packages.



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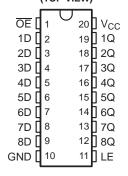
## 5 Revision History

<ul> <li>Removed Ordering Information table.</li> <li>Updated device temperature ratings.</li> <li>Added Handling Ratings.</li> <li>Added Typical Characteristics.</li> <li>Added Detailed Description section.</li> <li>Added Applications and Implementation section.</li> <li>Added Power Supply Recommendations section.</li> <li>Added Layout section.</li> </ul>	Cr	nanges from Revision R (September 2005) to Revision S	Page
<ul> <li>Added Handling Ratings.</li> <li>Added Typical Characteristics.</li> <li>Added Detailed Description section.</li> <li>Added Applications and Implementation section.</li> <li>Added Power Supply Recommendations section.</li> </ul>	•		
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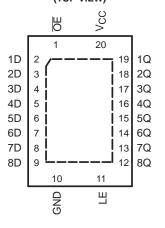


## 6 Pin Configuration and Functions

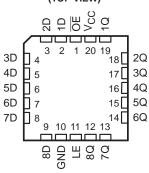
SN54LVC573A...J OR W PACKAGE SN74LVC573A...DB, DGV, DW, N, NS, OR PW PACKAGE (TOP VIEW)



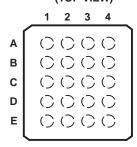
SN74LVC573A . . . RGY PACKAGE (TOP VIEW)



SN54LVC573A...FK PACKAGE (TOP VIEW)



GQN OR ZQN PACKAGE (TOP VIEW)



#### **Pin Functions**

PIN				
	SN54LVC573A	SN74LVC573A		DESCRIPTION
NAME	J, W, AND FK	DB, DGV, DW, N, NS, PW, AND RGY	GQN AND ZQN	
ŌĒ	1	1	A2	Enable Pin
1D	2	2	A1	Input 1
2D	3	3	В3	Input 2
3D	4	4	B1	Input 3
4D	5	5	C2	Input 4
5D	6	6	C1	Input 5
6D	7	7	D3	Input 6
7D	8	8	D1	Input 7
8D	9	9	E2	Input 8
GND	10	10	E1	Ground Pin
LE	11	11	E3	Latch Enable
8Q	12	12	E4	Output 8
7Q	13	13	D2	Output 7
6Q	14	14	D4	Output 6
5Q	15	15	C3	Output 5
4Q	16	16	C4	Output 4
3Q	17	17	B2	Output 3
2Q	18	18	B4	Output 2
1Q	19	19	A4	Output 1
V <sub>CC</sub>	20	20	А3	Power Pin

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## 7 Specifications

## 7.1 Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		-0.5	6.5	V
VI	Input voltage range (2)		-0.5	6.5	V
Vo	Voltage range applied to any output in the high-imped	dance or power-off state (2)	-0.5	6.5	V
Vo	Voltage range applied to any output in the high or low	v state <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		<b>-</b> 50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		<b>-</b> 50	mA
Io	Continuous output current			±50	mA
	Continuous current through V <sub>CC</sub> or GND			±100	mA
		DB package <sup>(4)</sup>		70	
		DGV package <sup>(4)</sup>		92	
		DW package <sup>(4)</sup>		58	
0	Dealers the read impadence	GQN or ZQN package <sup>(4)</sup>		78	°C // //
$\theta_{JA}$	Package thermal impedance	N package <sup>(4)</sup>		69	°C/W
		NS package <sup>(4)</sup>	60		
		PW package <sup>(4)</sup>	83		
		RGY package (5)			

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.
- (5) The package thermal impedance is calculated in accordance with JESD 51-5.

#### 7.2 Handling Ratings

			MIN	MAX	UNIT
T <sub>stg</sub>	Storage temperature rang	e	-65	150	°C
	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	0	2000	\/
V <sub>(ESD)</sub>	Electrostatic discharge Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	0	1000	V	

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as 500 V may actually have higher performance.

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<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Pins listed as 250 V may actually have higher performance.



## 7.3 Recommended Operating Conditions<sup>(1)</sup>

			SN54LV	SN54LVC573A		/C573A	
			MIN	MAX	MIN	MAX	UNIT
.,	Owner Lawrellians	Operating	2	3.6	1.65	3.6	V
$V_{CC}$	Supply voltage	Data retention only	1.5		1.5		V
		V <sub>CC</sub> = 1.65 V to 1.95 V			0.65 × V <sub>CC</sub>		
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$			1.7		V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		2		
		V <sub>CC</sub> = 1.65 V to 1.95 V				0.35 × V <sub>CC</sub>	
$V_{IL}$	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$				0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		0.8	
VI	Input voltage		0	5.5	0	5.5	V
.,	Outroot walke as	High or low state	0	$V_{CC}$	0	$V_{CC}$	V
V <sub>O</sub>	Output voltage	3-state	0	5.5	0	5.5	V
		V <sub>CC</sub> = 1.65 V				-4	
	High lovel output ourrest	V <sub>CC</sub> = 2.3 V				-8	<b>∞</b> Λ
I <sub>OH</sub>	High-level output current	$V_{CC} = 2.7 \text{ V}$		-12		-12	mA
		V <sub>CC</sub> = 3 V		-24		-24	
		V <sub>CC</sub> = 1.65 V				4	
I <sub>OL</sub>	Low lovel output ourrent	$V_{CC} = 2.3 \text{ V}$				8	A
	Low-level output current	$V_{CC} = 2.7 \text{ V}$		12		12	mA
		V <sub>CC</sub> = 3 V		24		24	
Δt/Δν	Input transition rise or fall rate	•		6		6	ns/V
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

#### 7.4 Thermal Information

		SN74LVC573A	
	THERMAL METRIC <sup>(1)</sup>	PW	UNIT
		20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	102.5	
$R_{\theta JCtop}$	Junction-to-case (top) thermal resistance	35.9	
$R_{\theta JB}$	Junction-to-board thermal resistance	53.5	°C/W
ΨЈТ	Junction-to-top characterization parameter	2.2	
$\Psi_{JB}$	Junction-to-board characterization parameter	52.9	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

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## 7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	TEST CONDITION		SN54LVC573A			SN74L	-VC573A			
PARAMETER	TEST CONDITION	S V <sub>CC</sub>	MIN	TYP <sup>(1)</sup>	MAX	MIN	TYP <sup>(1)</sup>	MAX	UNIT	
	1. 100	1.65 V to 3.6 V				V <sub>CC</sub> - 0.2				
	$I_{OH} = -100 \ \mu A$	2.7 V to 3.6 V	V <sub>CC</sub> - 0.2							
	$I_{OH} = -4 \text{ mA}$	1.65 V				1.2				
$V_{OH}$	$I_{OH} = -8 \text{ mA}$	2.3 V				1.7			V	
	1 12 m A	2.7 V	2.2			2.2				
	$I_{OH} = -12 \text{ mA}$ 3 V 2.4			2.4						
	$I_{OH} = -24 \text{ mA}$	3 V	2.2			2.2				
	1 400	1.65 V to 3.6 V						0.2		
	$I_{OL} = 100 \mu A$	2.7 V to 3.6 V			0.2				İ	
V	I <sub>OL</sub> = 4 mA	1.65 V						0.45	0.45 V	
$V_{OL}$	$I_{OL} = 8 \text{ mA}$	2.3 V						0.7		
	I <sub>OL</sub> = 12 mA	2.7 V			0.4			0.4		
	I <sub>OL</sub> = 24 mA	3 V			0.55			0.55		
l <sub>l</sub>	V <sub>I</sub> = 0 to 5.5 V	3.6 V			±5			±5	μΑ	
l <sub>off</sub>	$V_I$ or $V_O = 5.5 \text{ V}$	0						±10	μΑ	
l <sub>OZ</sub>	V <sub>O</sub> = 0 to 5.5 V	3.6 V			±15			±10	μA	
	V <sub>I</sub> = V <sub>CC</sub> or GND	0 201/			10			10		
I <sub>CC</sub>	$3.6 \text{ V} \le \text{V}_1 \le 5.5 \text{ V}^{(2)}$ $I_0 = 0$ $3.6 \text{ V}$	= 0 3.6 V			10			10	μΑ	
ΔI <sub>CC</sub>	One input at $V_{CC} - 0.6 \text{ V}$ , Other inputs at $V_{CC}$ or GNI	2.7 V to 3.6 V			500			500	μΑ	
Ci	$V_I = V_{CC}$ or GND	3.3 V		4			4		pF	
Co	$V_O = V_{CC}$ or GND	3.3 V		5.5			5.5		рF	

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. (2) This applies in the disabled state only.

#### 7.6 Timing Requirements, SN54LVC573A

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

		SN54LVC573A				
		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
		MIN	MAX	MIN	MAX	
t <sub>w</sub>	Pulse duration, LE high	3.3		3.3		ns
t <sub>su</sub>	Setup time, data before LE↓	2		2		ns
t <sub>h</sub>	Hold time, data after LE↓	2.5		2.5		ns

## 7.7 Timing Requirements, SN74LVC573A

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

					SN74L\	/C573A				
		V <sub>CC</sub> = ± 0.1	1.8 V 5 V	V <sub>CC</sub> = ± 0.2	2.5 V 2 V	V <sub>CC</sub> =	2.7 V	V <sub>CC</sub> = 3 ± 0.3	3.3 V 3 V	UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>w</sub>	Pulse duration, LE high	9		4		3.3		3.3		ns
$t_{su}$	Setup time, data before LE↓	6		4		2		2		ns
t <sub>h</sub>	Hold time, data after LE↓	4		2		1.5		1.5		ns

Product Folder Links: SN54LVC573A SN74LVC573A



### 7.8 Switching Characteristics, SN54LVC573A

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

			SN54LV	C573A		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 2.7 V	V <sub>CC</sub> = 3 ± 0.3	.3 V V	UNIT
			MIN MAX	MIN	MAX	
	D	0	7.7	1	6.9	20
t <sub>pd</sub>	LE	Q	8.4	1	7.7	ns
t <sub>en</sub>	ŌĒ	Q	8.5	1	7.5	ns
t <sub>dis</sub>	ŌĒ	Q	7	0.5	6.7	ns

#### 7.9 Switching Characteristics, SN74LVC573A

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

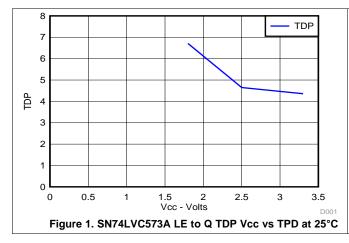
			SN74LVC573A									
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT	
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
	D	0	1	19.1	1	9.6	1	7.7	1.5	6.9		
t <sub>pd</sub>	LE	Q	1	22.8	1	10.5	1	8.4	2	7.7	ns	
t <sub>en</sub>	ŌĒ	Q	1	20	1	10.5	1	8.5	1.5	7.5	ns	
t <sub>dis</sub>	ŌĒ	Q	1	19.3	1	7.8	1	7	1.6	6.5	ns	
t <sub>sk(o)</sub>										1	ns	

## 7.10 Operating Characteristics

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT	
	Power dissipation  C <sub>pd</sub> capacitance  per latch	Outputs enabled	f = 10 MHz	61	56	37	, F
C <sub>pd</sub>		Outputs disabled	I = IU WINZ	3	3	4	pF

## 7.11 Typical Characteristics



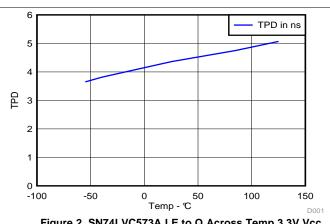
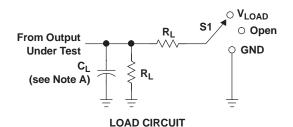


Figure 2. SN74LVC573A LE to Q Across Temp 3.3V Vcc

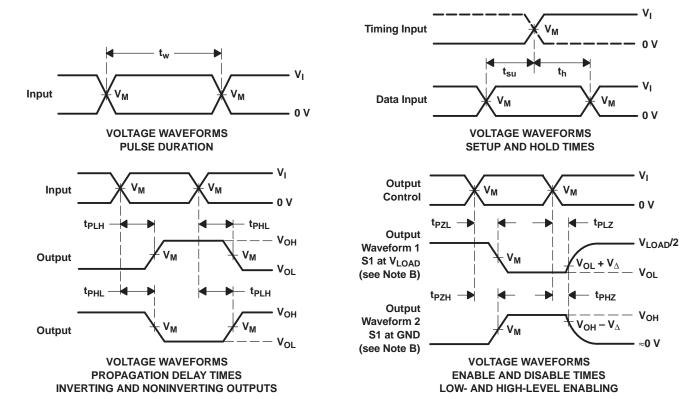


#### 8 Parameter Measurement Information



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

	INF	PUTS	.,	.,		-	, , , , , , , , , , , , , , , , , , ,
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	CL	R <sub>L</sub>	$V_{\!\scriptscriptstyle\Delta}$
1.8 V $\pm$ 0.15 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V $\pm$ 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



- NOTES: A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

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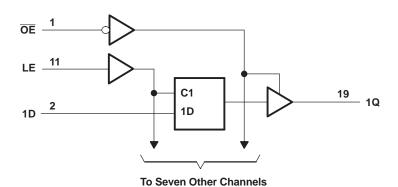


#### 9 Detailed Description

#### 9.1 Overview

The SN54LVC573A octal transparent D-type latch is designed for 2.7-V to 3.6-V  $V_{CC}$  operation, and the SN74LVC573A octal transparent D-type latch is designed for 1.65-V to 3.6-V  $V_{CC}$  operation. These devices feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, input/output (I/O) ports, bidirectional bus drivers, and working registers. While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels at the D inputs. A buffered output-enable ( $\overline{OE}$ ) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.  $\overline{OE}$  does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state. These devices are fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### 9.2 Functional Block Diagram



Pin numbers shown are for the DB, DGV, DW, FK, J, N, NS, PW, RGY, and W packages.

#### 9.3 Feature Description

- Wide operating voltage range
  - Operates from 1.65 V to 3.6 V
- Allows down voltage translation
  - Inputs accept voltages to 5.5 V
- I<sub>off</sub> Feature
  - Allows voltages on the inputs and outputs when V<sub>CC</sub> is 0 V

#### 9.4 Device Functional Modes

# Function Table (Each Latch)

	INPUTS	OUTPUT				
ŌĒ	LE	D	Q			
L	Н	Н	Н			
L	Н	L	L			
L	L	X	$Q_0$			
Н	Χ	X	Z			

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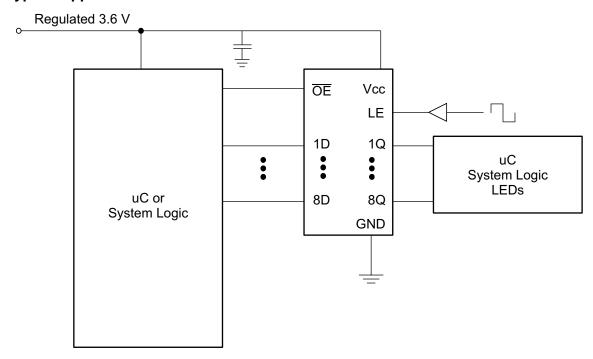


### 10 Applications and Implementation

#### 10.1 Application Information

The SN74LVC573A is a high drive CMOS device that can be used for a multitude of bus interface type applications where the data needs to be retained or latched . It can produce 24 mA of drive current at 3.3 V making it Ideal for driving multiple outputs and good for high speed applications up to 100 MHz. The inputs are 5.5 V tolerant allowing it to translate down to  $V_{\rm CC}$ .

### 10.2 Typical Application



#### 10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

#### 10.2.2 Detailed Design Procedure

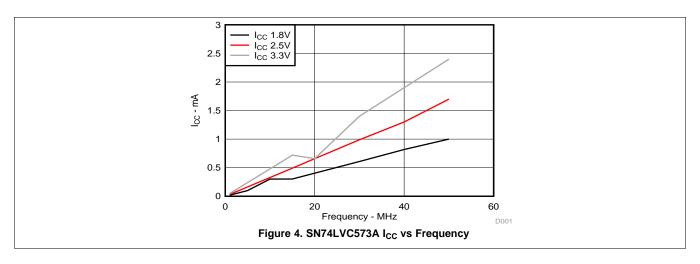
- 1. Recommended Input conditions
  - Rise time and fall time specifications. See (Δt/ΔV) in Recommended Operating Conditions table.
  - Specified high and low levels. See (V<sub>IH</sub> and V<sub>II</sub>) in Recommended Operating Conditions table.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5V at any valid  $V_{CC}$ .
- 2. Recommend output conditions
  - Load currents should not exceed 25 mA per output and 50 mA total for the part.
  - Outputs should not be pulled above V<sub>CC</sub>.

Submit Documentation Feedback



# Typical Application (continued)

## 10.2.3 Application Curves



### 11 Power Supply Recommendations

The power supply can be any voltage between the Min and Max supply voltage rating located in the Recommended Operating Conditions table.

Each V<sub>CC</sub> pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1-µF capacitor is recommended. If there are multiple VCC pins, then a 0.01-µF or 0.022-µF capacitor is recommended for each power pin. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

### 12 Layout

#### 12.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V<sub>CC</sub> whichever make more sense or is more convenient. It is generally OK to float outputs unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This will not disable the input section of the IOs so they also cannot float when disabled.

#### 12.2 Layout Example



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### 13 Device and Documentation Support

#### 13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN54LVC573A	Click here	Click here	Click here	Click here	Click here	
SN74LVC573A	Click here	Click here	Click here	Click here	Click here	

#### 13.2 Trademarks

All trademarks are the property of their respective owners.

#### 13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms and definitions.

## 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

2 Submit Documentation Feedback





17-Mar-2017

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9757501Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9757501Q2A SNJ54LVC 573AFK	Samples
5962-9757501QRA	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9757501QR A SNJ54LVC573AJ	Samples
5962-9757501QSA	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9757501QS A SNJ54LVC573AW	Samples
SN74LVC573ADBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573ADBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573ADGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573ADGVRE4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573ADW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC573A	Samples
SN74LVC573ADWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC573A	Samples
SN74LVC573ADWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC573A	Samples
SN74LVC573AN	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 125	SN74LVC573AN	Samples
SN74LVC573ANSR	ACTIVE	so	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC573A	Samples
SN74LVC573ANSRE4	ACTIVE	so	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC573A	Samples
SN74LVC573APW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573APWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples





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17-Mar-2017

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LVC573APWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573APWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573APWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573APWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573APWT	ACTIVE	TSSOP	PW	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573APWTG4	ACTIVE	TSSOP	PW	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC573A	Samples
SN74LVC573ARGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LC573A	Samples
SN74LVC573AZQNR	ACTIVE	BGA MICROSTAR JUNIOR	ZQN	20	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	LC573A	Samples
SNJ54LVC573AFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9757501Q2A SNJ54LVC 573AFK	Samples
SNJ54LVC573AJ	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9757501QR A SNJ54LVC573AJ	Samples
SNJ54LVC573AW	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9757501QS A SNJ54LVC573AW	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

## PACKAGE OPTION ADDENDUM



17-Mar-2017

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN54LVC573A, SN74LVC573A:

Catalog: SN74LVC573A

Automotive: SN74LVC573A-Q1, SN74LVC573A-Q1

Enhanced Product: SN74LVC573A-EP, SN74LVC573A-EP

Military: SN54LVC573A

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product



## **PACKAGE OPTION ADDENDUM**

17-Mar-2017

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 6-May-2017

## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC573ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVC573ADGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC573ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVC573ANSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVC573APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LVC573APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LVC573APWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LVC573ARGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1
SN74LVC573AZQNR	BGA MI CROSTA R JUNI OR	ZQN	20	1000	330.0	12.4	3.3	4.3	1.6	8.0	12.0	Q1

www.ti.com 6-May-2017



\*All dimensions are nominal

All difficusions are norminal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC573ADBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74LVC573ADGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0
SN74LVC573ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVC573ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LVC573APWR	TSSOP	PW	20	2000	364.0	364.0	27.0
SN74LVC573APWR	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74LVC573APWT	TSSOP	PW	20	250	367.0	367.0	38.0
SN74LVC573ARGYR	VQFN	RGY	20	3000	367.0	367.0	35.0
SN74LVC573AZQNR	BGA MICROSTAR JUNIOR	ZQN	20	1000	336.6	336.6	28.6

## W (R-GDFP-F20)

## CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

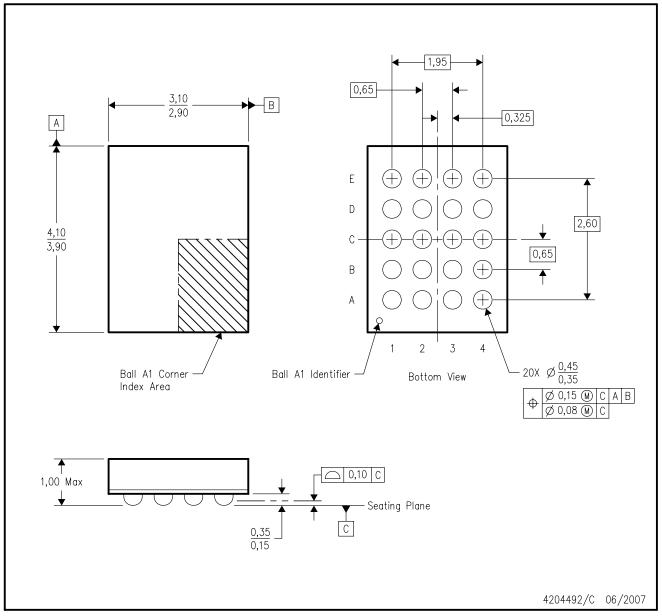
  D. Index point is provided on cap for terminal identification only.

  E. Falls within Mil—Std 1835 GDFP2—F20



# ZQN (R-PBGA-N20)

## PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BC-2.
- D. This package is lead-free. Refer to the 20 GQN package (drawing 4200704) for tin-lead (SnPb).



## FK (S-CQCC-N\*\*)

## LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



## RGY (R-PVQFN-N20)

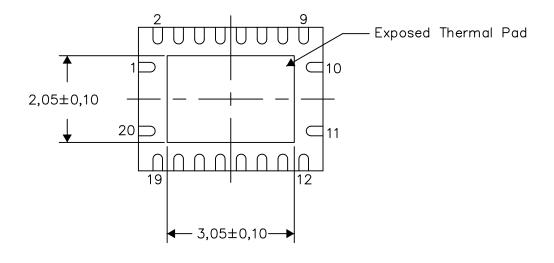
#### PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

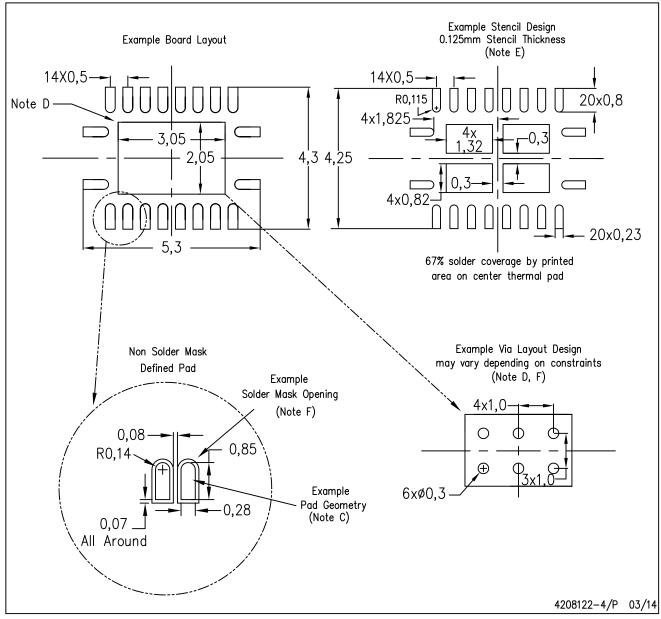
4206353-4/P 03/14

NOTE: All linear dimensions are in millimeters



## RGY (R-PVQFN-N20)

## PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="https://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



## 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## DGV (R-PDSO-G\*\*)

#### **24 PINS SHOWN**

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194 PW (R-PDSO-G20)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G20)

## PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## DB (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE

#### **28 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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